



## LITE-ON **SEMICONDUCTOR**

# SBL20V60CT

SCHOTTKY BARRIER RECTIFIERS	REVERSE VOLTAGE – 60 Volts FORWARD CURRENT – 20 Amperes								
<ul> <li>FEATURES</li> <li>Metal of silicon rectifier, majority carrier conduction</li> <li>Guard ring for transient protection</li> <li>Low power loss, high efficiency</li> <li>High current capability, low VF</li> <li>High surge capacity</li> <li>Plastic package has UL flammability classification 94V-0</li> <li>For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications</li> <li>Lead-Free Finish; RoHS Compliant (Notes 1 &amp; 2)</li> <li>MECHANICAL DATA</li> <li>Package: TO-220AB molded plastic</li> <li>Polarity: As marked on the body</li> <li>Weight: 0.08 ounces, 2.24 grams</li> <li>Mounting position: Any</li> </ul>	TO-220AB         DIM. MIN. MAX.         A       14.22       15.88         B       9.65       10.67         C       22.54       3.43         D       5.84       6.86         E       8.26       9.28         F       2.635       G       12.70       14.73         H       2.29       2.79       1       0.51       1.14         J       0.30       0.64       K       3.53.Ø       4.09.Ø         L       3.56       4.83       M       1.14       1.40								
• Max. mounting torque = 0.5 N.m (5.1 Kgf-cm)	PIN 1 OPIN 2 PIN 3 OPIN 2 CASE All Dimensions in millimeter								
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS         Ratings at 25°C ambient temperature unless otherwise specified.									

CHARACTERISTICS	SYMBOL	SBL20V60CT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	60	V
Maximum RMS Voltage	VRMS	42	V
Maximum DC Blocking Voltage	VDC	60	V
Maximum Average Forward Rectified Current (See Fig.1) @TC=125°C	I(AV)	20	А
Peak Forward Surge Current 8.3ms single half sine-wave @Tj=25°C	IFSM	200	А
Maximum Forward Voltage @Tj=25°C at 10A DC (Note 3) @Tj=125°C	VF	0.60 0.55	V
Maximum DC Reverse Current @Tj=25°C at Rated DC Blocking Voltage @Tj=100°C	IR	0.1 20	mA
Typical Junction Capacitance per element (Note 4)	CJ	430	РF
Typical Thermal Resistance (Note 5)	R⊖JC	2.0	°C/W
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	Тѕтс	-55 to +150	°C

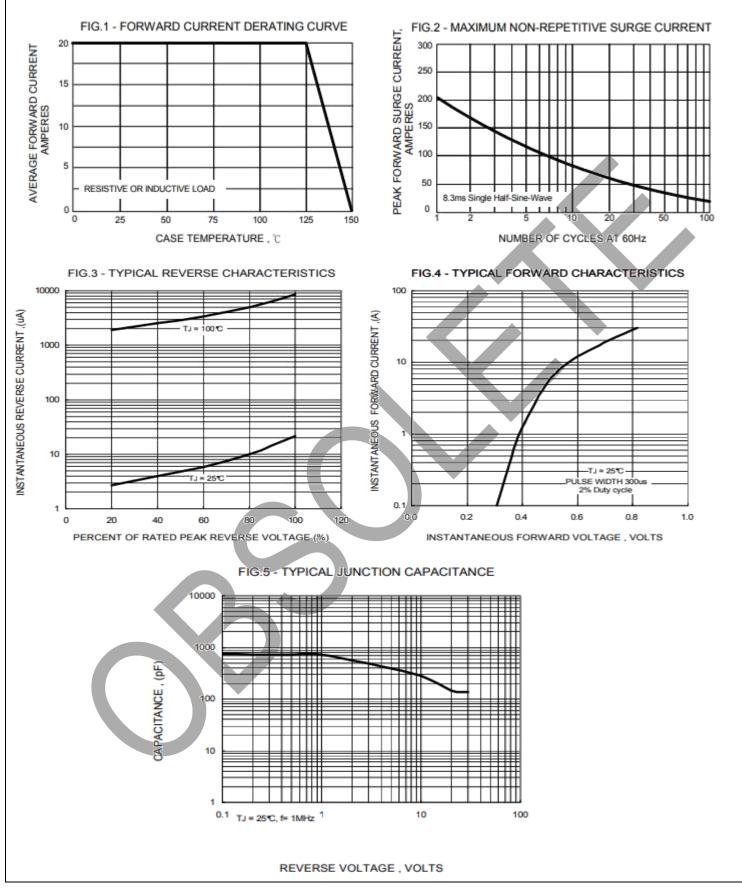
#### Notes:

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 300us Pulse Width, 2% Duty Cycle.
 Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 Device mounted on 75mm x 1.6mm Cu plate.



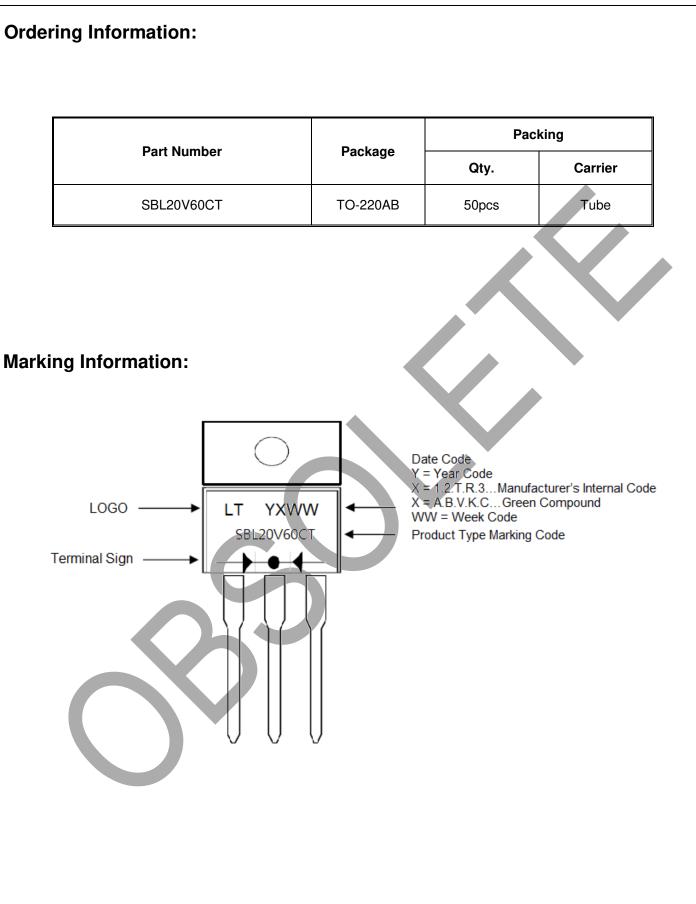
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